

SUP50N03-5M1P-GE3

SUP50N03-5M1P-GE3 Information

	TO-220-3 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SUP50N03-5M1P-GE3 Specifications

Manufacturer Part Number	SUP50N03-5M1P-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	TrenchFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	66nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2780pF @ 15V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.7W (Ta), 59.5W (Tc)
Rds On (Max) @ Id, Vgs	5.1 mOhm @ 22A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

SUP50N03-5M1P-GE3 Guarantees



Quality Guarantees

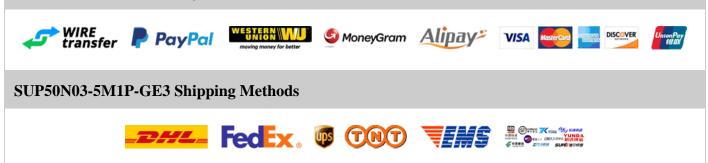
We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SUP50N03-5M1P-GE3 Payment Methods



If you have any question about SUP50N03-5M1P-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com